NSN 5962-01-080-6175

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-080-6175

Body Length:

Between 0.370 inches and 0.410 inches

Body Width:

Between 0.245 inches and 0.280 inches

Body Height:

Between 0.030 inches and 0.070 inches

Maximum Power Dissipation Rating:

256.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Countermeasures set, type an/alq-137

Features Provided:

Hermetically sealed and monolithic and positive outputs and low power and schottky and 3-state output and programmed and programmable

and bipolar and w/decoded output and w/enable and w/storage and expandable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

6 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Test Data Document:

94117-310412 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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